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Vishay Siliconix

SiZ904DT

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static				•	•			
Drain-source breakdown voltage	V	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	Ch-1	30	-	-	v	
	V <sub>DS</sub>	$V_{GS} = 0 V, I_D = 250 \mu A$	Ch-2	30	-	-	v	
V to many and the second initialized	N/ /T	I <sub>D</sub> = 250 μA	Ch-1	-	35	-		
V <sub>DS</sub> temperature coefficient	$\Delta V_{DS}/T_{J}$	I <sub>D</sub> = 250 μA	Ch-2	-	33	-		
		I <sub>D</sub> = 250 μA	Ch-1	-	-4.5	-	mV/°C	
V <sub>GS(th)</sub> temperature coefficient	$\Delta V_{GS(th)}/T_J$	I <sub>D</sub> = 250 μA	Ch-2	-	-5	-		
		$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	Ch-1	1	-	2.5	V	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	Ch-2	1.2	-	2.5		
	I <sub>GSS</sub>		Ch-1	-	-	± 100	nA	
Gate-body leakage		$V_{DS} = 0 \text{ V},  V_{GS} = \pm 20 \text{ V}$	Ch-2	-	-	± 100		
		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	Ch-1	-	-	1	1	
7		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	Ch-2	-	-	1	μA	
Zero gate voltage drain current	IDSS	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$	Ch-1	-	-	5		
	-	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$	Ch-2	-	-	5		
		$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	Ch-1	20	-	-		
On-state drain current <sup>b</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	Ch-2	20	-	-	A	
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7.8 A	Ch-1	-	0.0200	0.0240		
	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A}$	Ch-2	-	0.0105	0.0135	- <u>O</u>	
Drain-source on-state resistance b		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 7 \text{ A}$	Ch-1	-	0.0240	0.0300		
	-	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 7 \text{ A}$	Ch-2	-	0.0135	0.0170		
		V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.8 A	Ch-1	-	17	-		
Forward transconductance <sup>b</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A}$	Ch-2	-	24	-	S	
Dynamic <sup>a</sup>				•			•	
	0		Ch-1	-	435	-		
Input capacitance	C <sub>iss</sub>	Channel-1	Ch-2	-	846	-	pF	
Output capacitance	C <sub>oss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$	Ch-1	-	95	-		
		Channel-2	Ch-2	-	187	-		
Reverse transfer capacitance	C <sub>rss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$	Ch-1	-	42	-		
			Ch-2	-	72	-		
Total gate charge		$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 7.8 \text{ A}$	Ch-1	-	8	12		
	Q <sub>g</sub>	$V_{DS} = 15 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 10 \text{ A}$	Ch-2	-	15.4	23	- nC	
			Ch-1	-	3.8	6		
		Channel-1	Ch-2	-	7.3	11		
Gate-source charge	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 7.8 \text{ A}$	Ch-1	-	1.4	-		
		Channel-2	Ch-2	-	2.3	-		
	Q <sub>gd</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$	Ch-1	-	1.1	-		
Gate-drain charge			Ch-2	-	2.2	-		
			Ch-1	0.6	3.2	6.4		
Gate resistance	R <sub>g</sub>	f = 1 MHz	Ch-2	0.2	0.8	1.6	Ω	

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## SiZ904DT

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PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNIT
Dynamic <sup>a</sup>					•		
Turn-on delay time	+ <i>u</i> _ >		Ch-1	-	15	30	
rum-on delay time	t <sub>d(on)</sub>	Channel-1	Ch-2	-	15	30	
Rise time	t <sub>r</sub>	$V_{DD} = 15 \text{ V}, \text{ R}_{L} = 2.4 \Omega$	Ch-1	-	12	24	
	٩	$I_D \cong 6.3$ A, $V_{GEN}$ = 4.5 V, $R_g$ = 1 $\Omega$	Ch-2	-	12	24	
Turn-off delay time	t <sub>d(off)</sub>	Channel-2	Ch-1	-	13	26	
· · · · · · · · · · · · · · · · · · ·	-0(01)	$V_{DD}$ = 15 V, $R_L$ = 1.5 $\Omega$ $I_D \cong$ 10 A, $V_{GEN}$ = 4.5 V, $R_q$ = 1 $\Omega$	Ch-2	-	13	26	
Fall time	t <sub>f</sub>	$I_D = 10 \text{ A}, V_{\text{GEN}} = 4.5 \text{ V}, R_g = 1.52$	Ch-1	-	10	20	
	'		Ch-2	-	10	20	ns
Turn-on delay time	t <sub>d(on)</sub>		Ch-1	-	5	10	
	-0(01)	Channel-1	Ch-2	-	9	18	
Rise time	t <sub>r</sub>	$\label{eq:VDD} \begin{array}{l} V_{DD} = 15 \; V, \; R_L = 2.4 \; \Omega \\ I_D \cong 6.3 \; A, \; V_GEN = 10 \; V, \; R_g = 1 \; \Omega \end{array}$	Ch-1	-	10	20	
		ID = 0.3 A, VGEN = 10 V, Hg = 1.32	Ch-2	-	9	18	
Turn-off delay time	t <sub>d(off)</sub>	Channel-2	Ch-1	-	15	30	
-	t <sub>f</sub>	$V_{DD}$ = 15 V, $R_L$ = 1.5 $\Omega$ $I_D \cong$ 10 A, $V_{GEN}$ = 10 V, $R_q$ = 1 $\Omega$	Ch-2	-	14	28	
Fall time			Ch-1 Ch-2	-	10 8	20 16	
Drain-Source Body Diode Characterist	ics		Cn-2	-	0	10	
Brain-Source Body Blode Characterist			Ch-1	-	-	12	
Continuous source-drain diode current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	Ch-2	-	-	16	-
			Ch-1	_	-	30	A
Pulse diode forward current <sup>a</sup>	I <sub>SM</sub>	Ch		-	-	40	
Body diode voltage	V <sub>SD</sub>	I <sub>S</sub> = 6.3 A, V <sub>GS</sub> = 0 V	Ch-1	-	0.8	1.2	
		$I_{\rm S} = 3 \text{ A}, V_{\rm GS} = 0 \text{ V}$	Ch-2	-	0.78	1.2	V
Body diode reverse recovery time	t <sub>rr</sub>		Ch-1	-	15	30	
		Channel-1	Ch-2	-	17	34	ns
Body diode reverse recovery charge	Q <sub>rr</sub>	$I_{\rm F} = 6.3 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	Ch-1	-	7	15	-
		T <sub>J</sub> = 25 °C	Ch-2	-	9.5	19	nC
Reverse recovery fall time	t <sub>a</sub>	Channel-2	Ch-1	-	9	-	
		$I_F = 10 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s},$	Ch-2	-	10	-	
Reverse recovery rise time	t <sub>b</sub>	$T_J = 25 \ ^{\circ}C$	Ch-1	-	6	-	ns
			Ch-2	-	7	-	1

#### Notes

a. Guaranteed by design, not subject to production testing

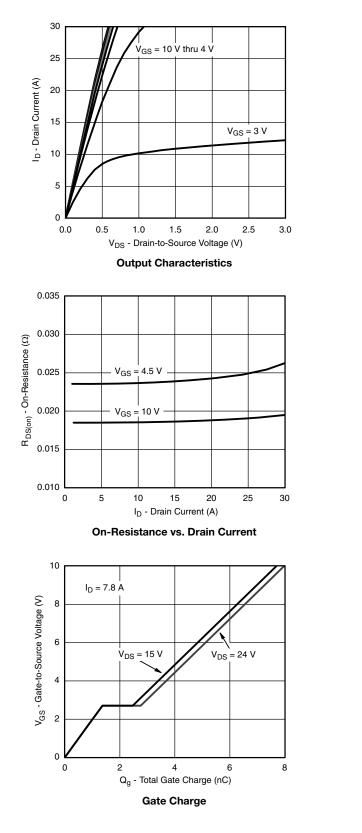
b. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %

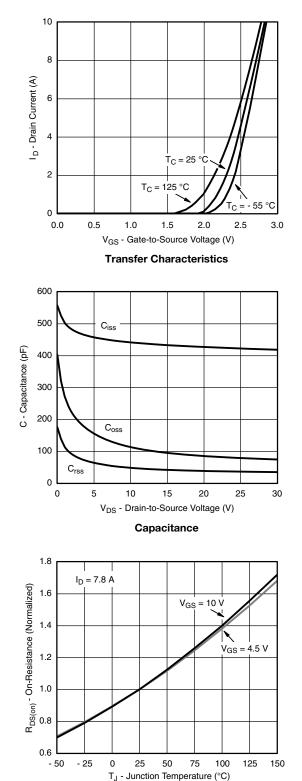
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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## CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





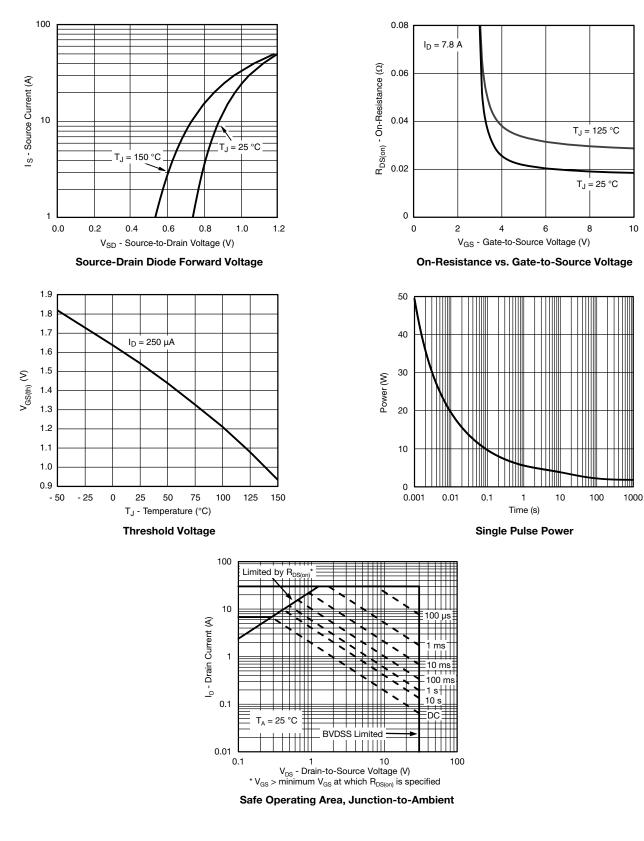
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## CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



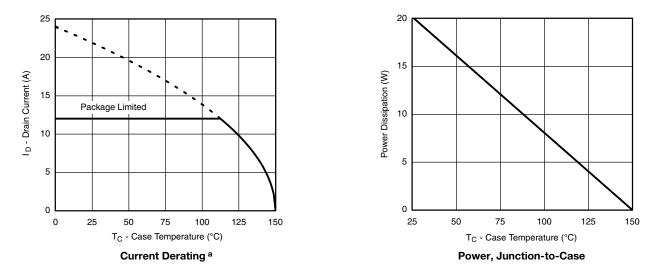
5



SiZ904DT

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### CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

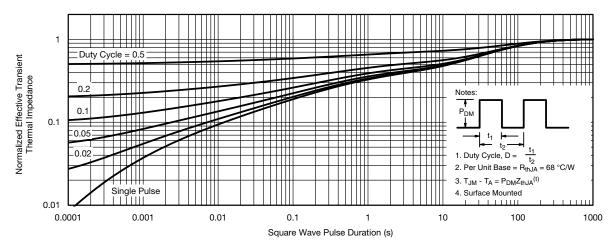


#### Note

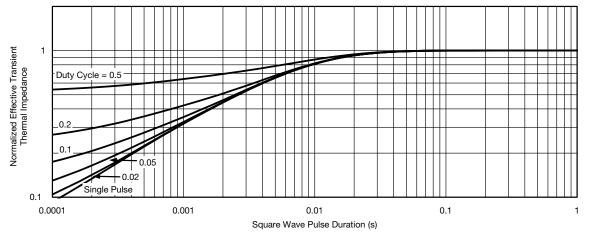
a. The power dissipation P<sub>D</sub> is based on T<sub>J</sub> max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



## CHANNEL-1 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

S11-2380-Rev. B, 28-Nov-11

Downloaded from Arrow.com.



- 55 °C

4

5

 $T_{C}$ =

3

20

 $V_{GS} = 10 V$ 

V<sub>GS</sub> = 4.5 V

100

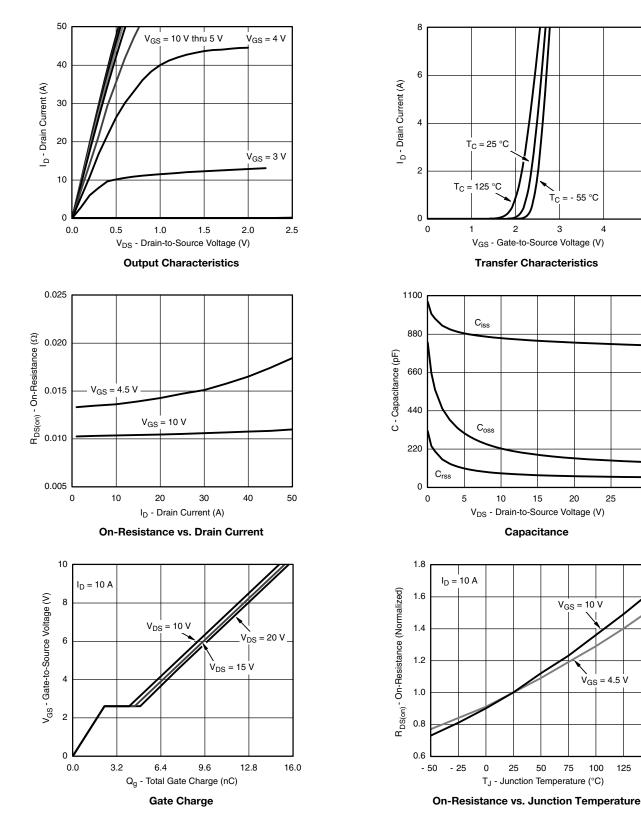
75

125 150

25

30

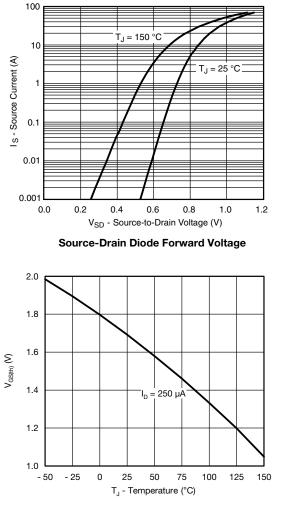
### CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



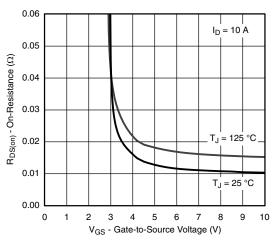
8



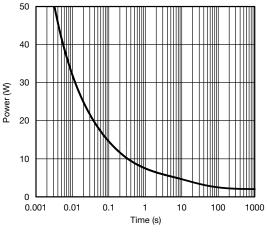
### CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



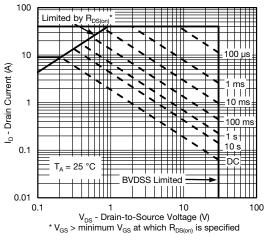
**Threshold Voltage** 



**On-Resistance vs. Gate-to-Source Voltage** 





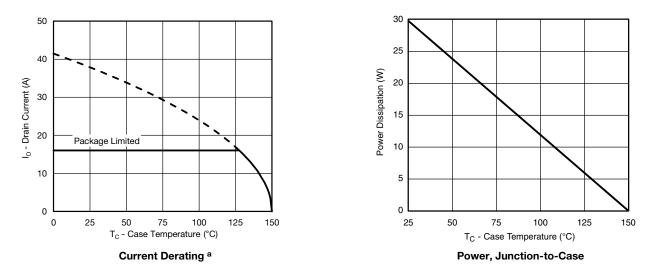


Safe Operating Area, Junction-to-Ambient

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### CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

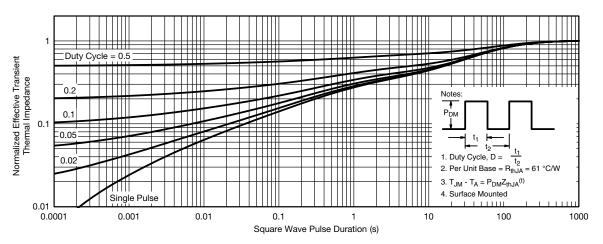


#### Note

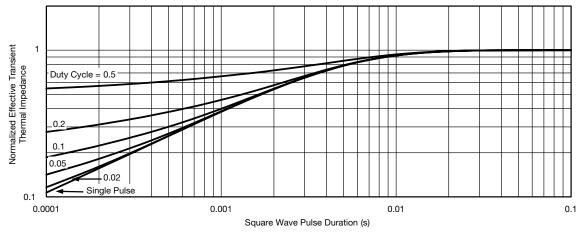
a. The power dissipation P<sub>D</sub> is based on T<sub>J</sub> max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit



#### CHANNEL-2 TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



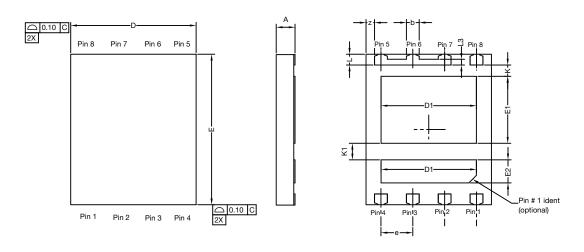
Normalized Thermal Transient Impedance, Junction-to-Case

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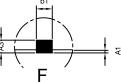
# PowerPAIR<sup>®</sup> 6 x 5 Case Outline



Top side view







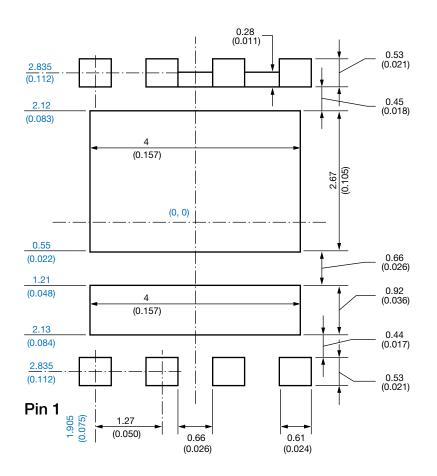
		MILLIMETERS		INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	0.70	0.75	0.80	0.028	0.030	0.032		
A1	0.00	-	0.10	0.000	-	0.004		
A3	0.15	0.20	0.25	0.006	0.007	0.009		
b	0.43	0.51	0.61	0.017	0.020	0.024		
b1		0.25 BSC			0.010 BSC			
D	4.90	5.00	5.10	0.192	0.196	0.200		
D1	3.75	3.80	3.85	0.148	0.150	0.152		
E	5.90	6.00	6.10	0.232	0.236	0.240		
E1 Option AA (for W/B)	2.62	2.67	2.72	0.103	0.105	0.107		
E1 Option AB (for BWL)	2.42	2.47	2.52	0.095	0.097	0.099		
E2	0.87	0.92	0.97	0.034	0.036	0.038		
е		1.27 BSC			0.050 BSC			
K Option AA (for W/B)		0.45 typ.			0.018 typ.			
K Option AB (for BWL)		0.65 typ.			0.025 typ.			
K1		0.66 typ.			0.025 typ.			
L	0.33	0.43	0.53	0.013	0.017	0.020		
L3	0.23 BSC			0.009 BSC				
Z		0.34 BSC			0.013 BSC			

Revision: 22-Dec-14

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# **Recommended Minimum PAD for PowerPAIR® 6 x 5**



Dimensions in millimeters (inch)

#### Note

• Linear dimensions are in black, the same information is provided in ordinate dimensions which are in blue.



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